

DOCKET NO.: 215878US99DIV

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2-12-02  
Esther

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

IN RE APPLICATION OF: : EXAMINER

JAMAL RAMDANI

SERIAL NO.: NEW DIVISIONAL APPL. :

FILED: HEREWITH : GROUP ART UNIT

FOR: SEMICONDUCTOR STRUCTURE, SEMICONDUCTOR DEVICE,  
COMMUNICATING DEVICE, INTEGRATED CIRCUIT, AND PROCESS  
FOR FABRICATING THE SAME

PRELIMINARY AMENDMENT

Sir:

Prior to examination on the merits Applicants request entry of the following  
amendment.

IN THE INVENTORSHIP

A separate paper deleting Kurt W. Eisenbeiser has been submitted herewith.  
His invention is not being claimed herein.

IN THE CLAIMS

Please cancel Claims 1-143.

Please add new 144-163 as follows:

--144. A semiconductor structure comprising:

a monocrystalline silicon substrate;

an amorphous oxide material overlying the monocrystalline silicon substrate;

A'